

**IEEE SW Test Workshop**  
Semiconductor Wafer Test Workshop



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**CVInc**

# **Overpad Metallizations and Probe Challenges**

20<sup>th</sup> 2-0-1-0  
ANNIVERSARY

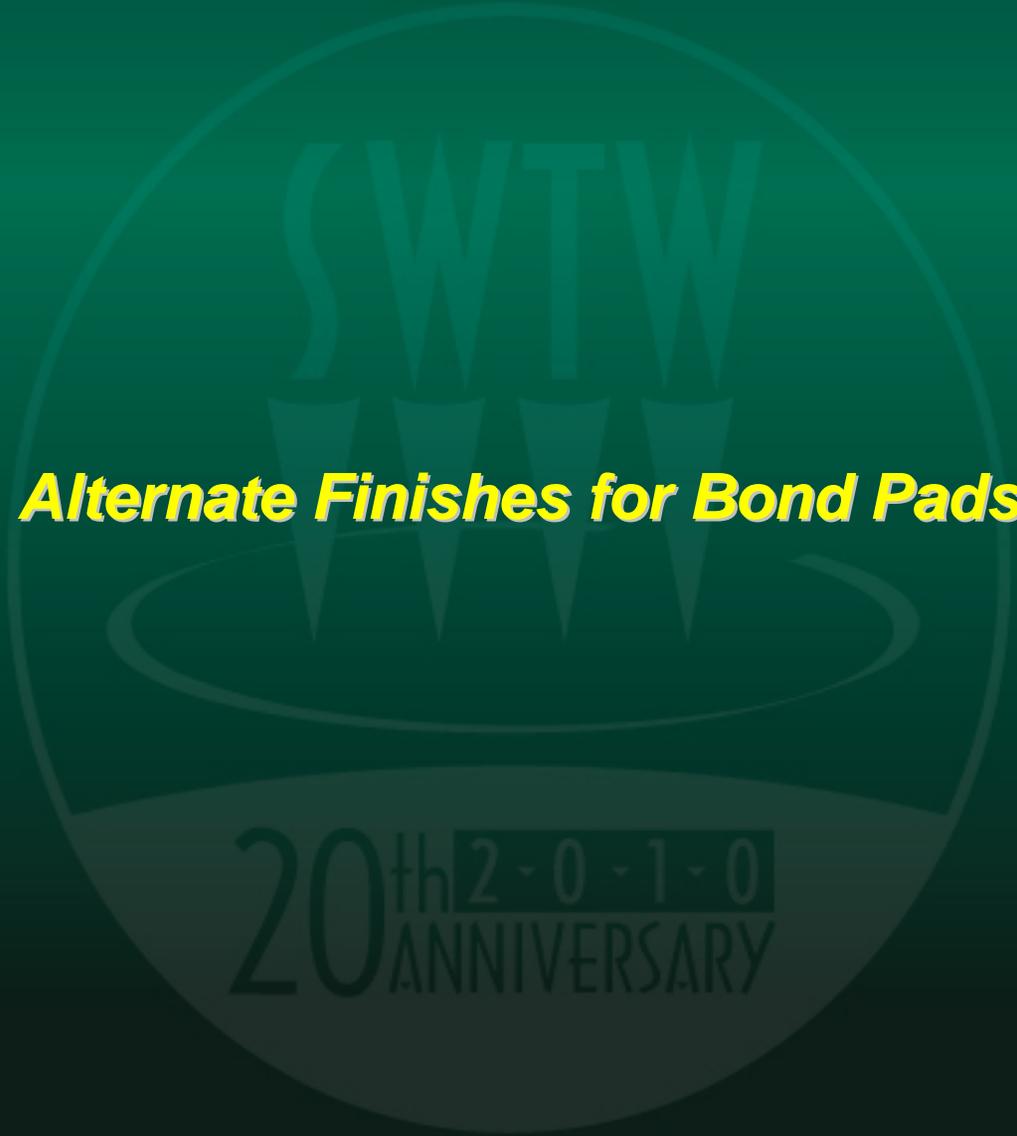
**June 6 to 9, 2010**

**San Diego, CA USA**

# Why Packaging “stuff” at Probe Conference

- More and more wafers with ENIG finish
- Reliability data applicable to contactor finishes for probes and sockets
- Metal to metal interactions extrapolate to probe and test





## ***Alternate Finishes for Bond Pads***



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# Probing and Wirebond of Al

- If its wirebondable.....its probable!
- Root cause of both wire bond and probe issues lies at the corrosion layer at the surface of the aluminum pads.
- Eliminate the aluminum or corrosion layer and probe “should” improve.



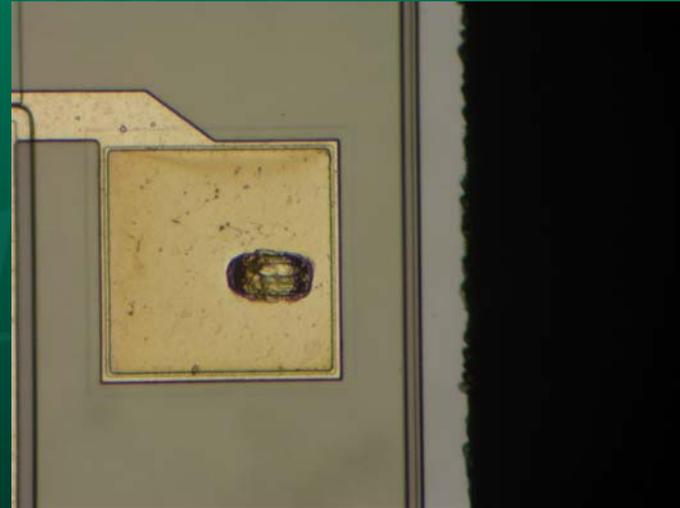
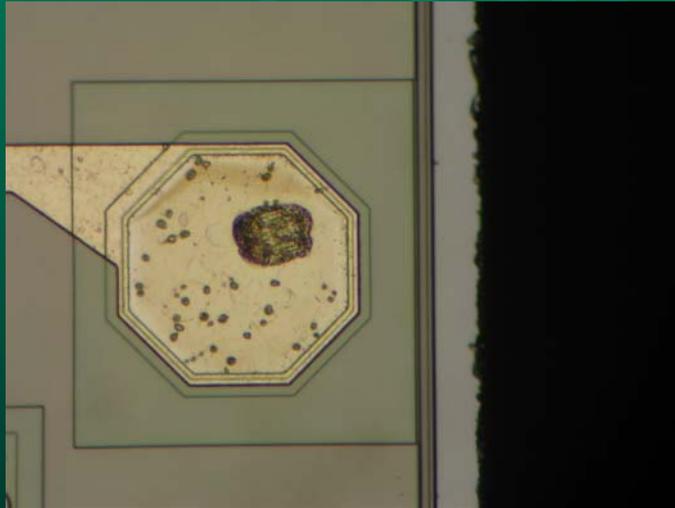
# ENIG or ENIPIG Instead of Al Pads

- ENIPIG has the following advantages compared to standard Al pads in standard and high temp applications:
- Gold wire bondable at all stages in the process
- No corrosion of the electroless nickel
- Excellent heat resistance
- **ENIG can also be applied to Copper and Steel**
- At probe:
- Probing on Au versus Al
- Optimized probe conditions and reduced cycle time

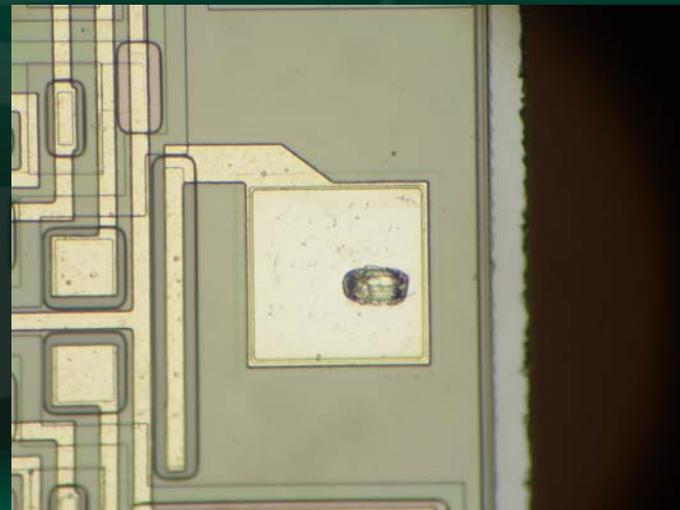
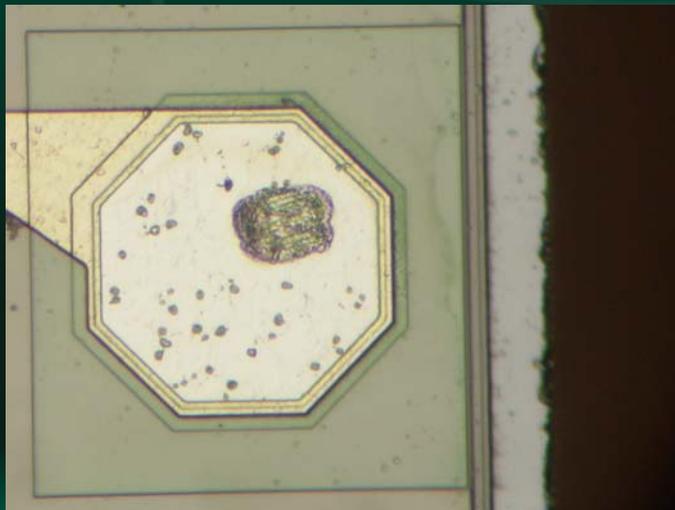


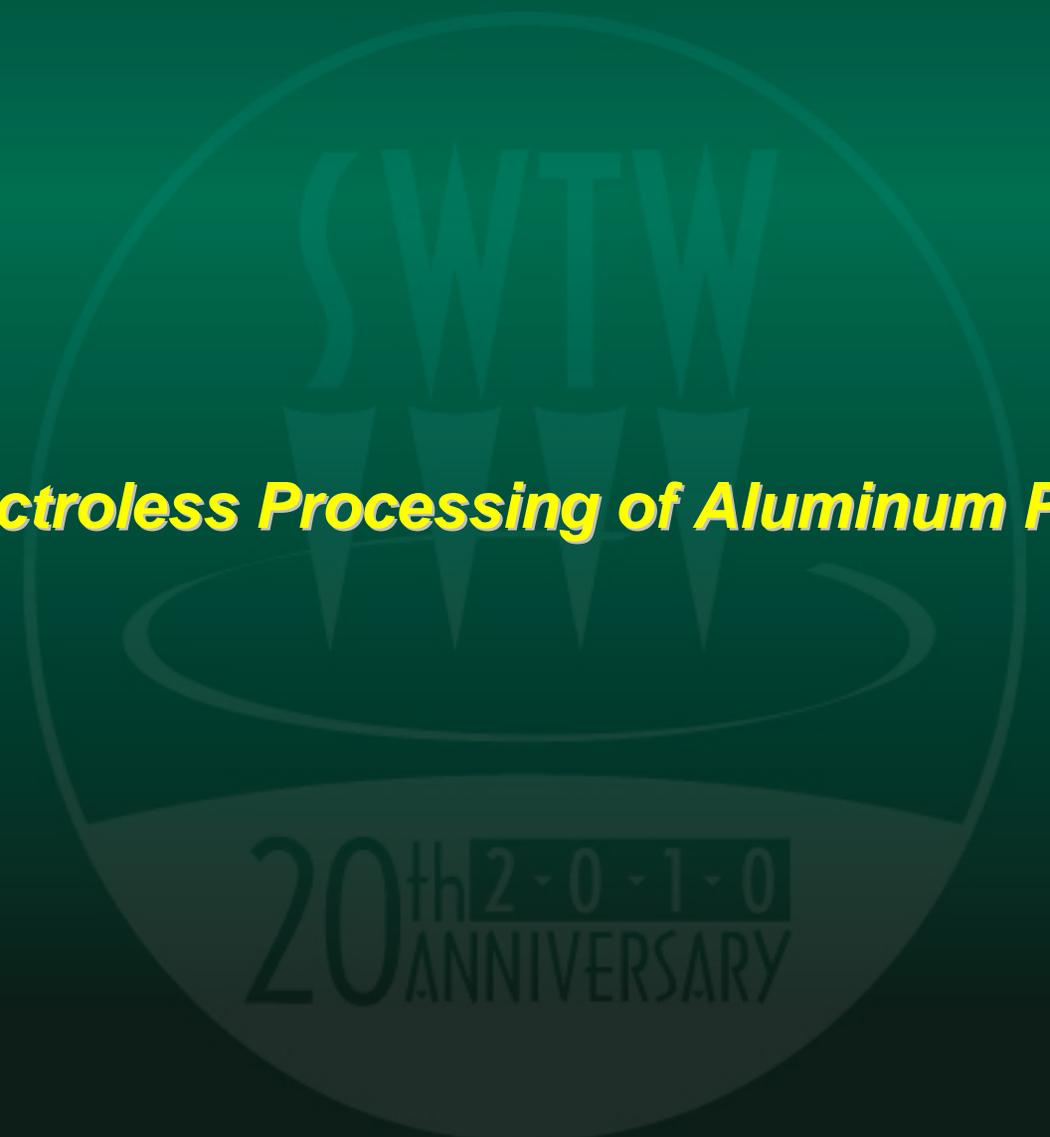
# Cleaning Improvements

As  
Recvd



BPS100  
5min





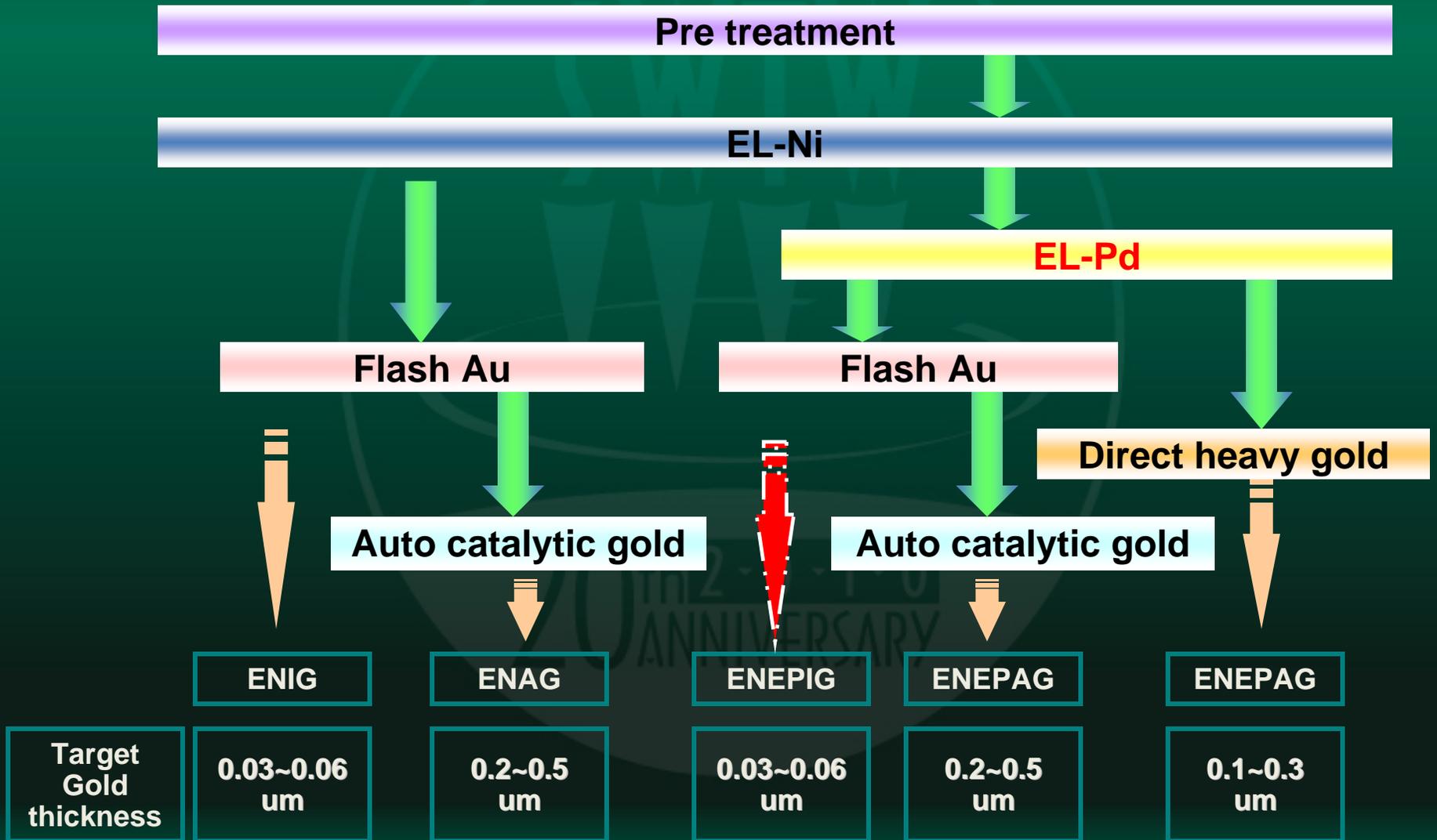
# ***Electroless Processing of Aluminum Pads***



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# Process for Plating Electroless NiAu NiPdAu



# Wire Bonding Reliability Test Condition

## Wire bonding condition

Equipment: TPT HB16 (semi-auto wire bonder)

Capillary: B1014-51-18-12(PECO)

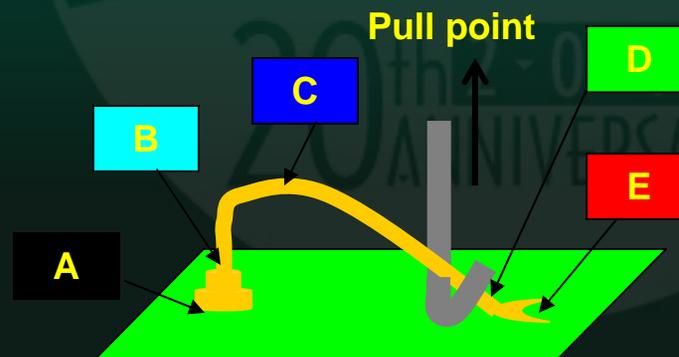
Wire: 1mil-gold Stage temperature: 150 deg.C

Ultra Sonic: 250mW (1<sup>st</sup>), 250mW (2<sup>nd</sup>)

Bonding Time: 200msec (1<sup>st</sup>), 50msec (2<sup>nd</sup>)

Loading force: 25g (1<sup>st</sup>), 50g (2<sup>nd</sup>)

Step: 0.700mm (1<sup>st</sup> to 2<sup>nd</sup> wire length)



# Results of Wire Bond Pull Test

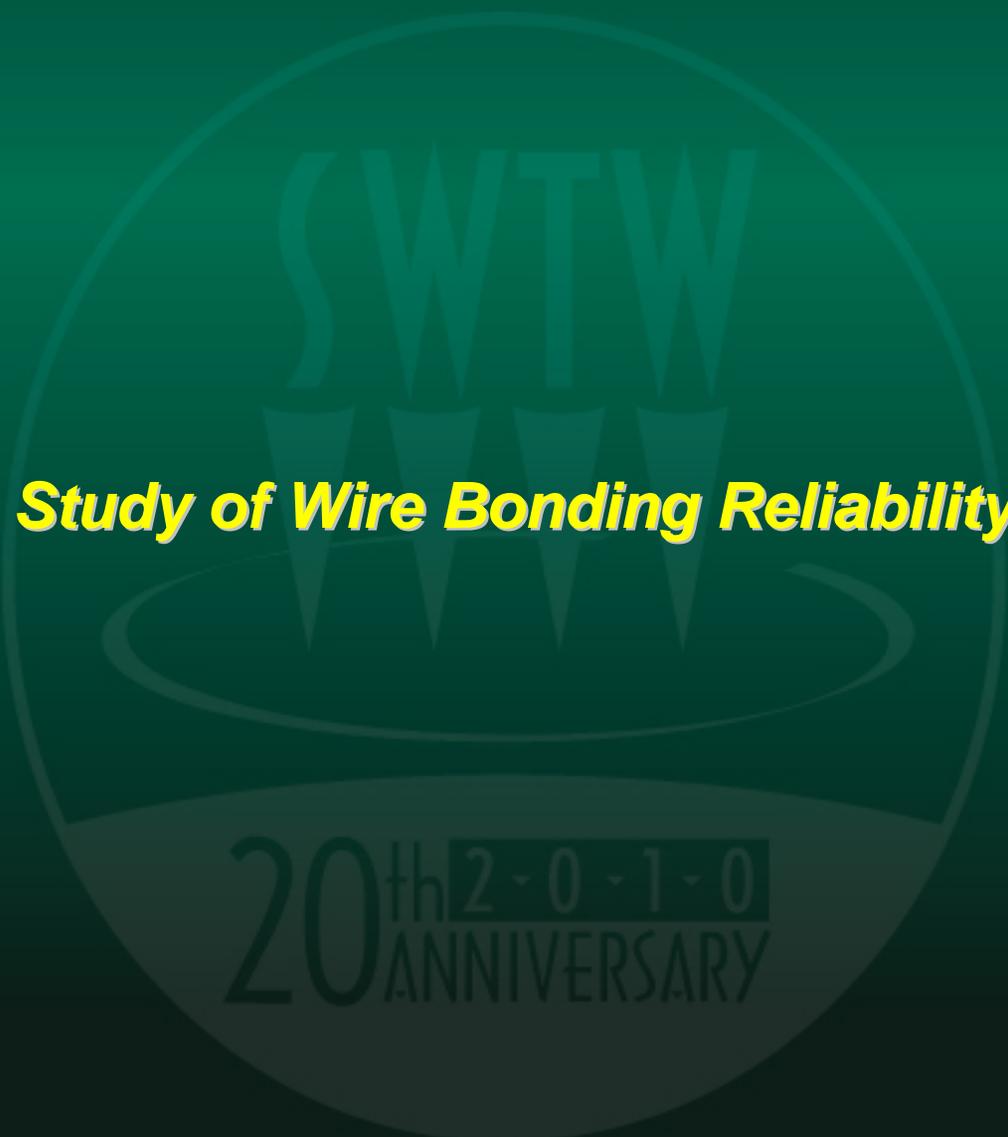
Heating treatment;175deg.C-16hr.

		Au thickness (um)								
		0.03	0.05	0.07	0.1	0.15	0.2	0.25	0.3	0.4
Pd thickness (um)	0	*	4.3	4.4	3.9	3.8	3.7	5.1	8.6	9.1
	0.01	6.8	7.9	7.9	8.1	8.7	8.6	9.6	10.6	10.5
	0.02	6.7	7.9	8.6	8.2	8.5	9.0	9.5	10.2	10.7
	0.03	6.0	7.7	8.4	8.2	8.2	9.3	9.3	10.7	10.4
	0.05	6.8	7.6	8.9	8.1	8.2	9.1	9.3	10.1	10.6
	0.07	7.0	7.8	8.1	8.3	8.8	9.5	9.1	10.9	11.1
	0.10	6.0	6.7	8.1	8.3	8.4	9.3	9.2	10.0	10.8
	0.12	7.2	8.4	8.9	8.8	8.9	9.5	9.6	10.9	10.5
	0.15	6.5	8.5	8.6	8.0	9.1	9.4	10.2	10.3	10.7
	0.20	6.0	8.8	8.9	8.7	9.1	9.4	10.0	10.3	10.5
	0.30	6.6	8.8	8.5	8.3	9.0	9.6	10.0	10.2	10.6

AVG. strength (g)	
more than 10	
9 ~ 10	
8 ~ 9	
6 ~ 8	
less than 6	
*	cannot bond

- Pd provides an excellent barrier to Ni migration through the Au
- 15 minutes in the Pd bath typically provides 0.2um of Pd.
- Wire bonding strength for ENEPIG is higher than ENIG even with thin Pd thickness range.
- Au thickness increase shows improvement in wire bond strength while Pd thickness increase does not.
- Thin layer of Pd or thick gold layer. Economics or cycle time decision





# ***Study of Wire Bonding Reliability***

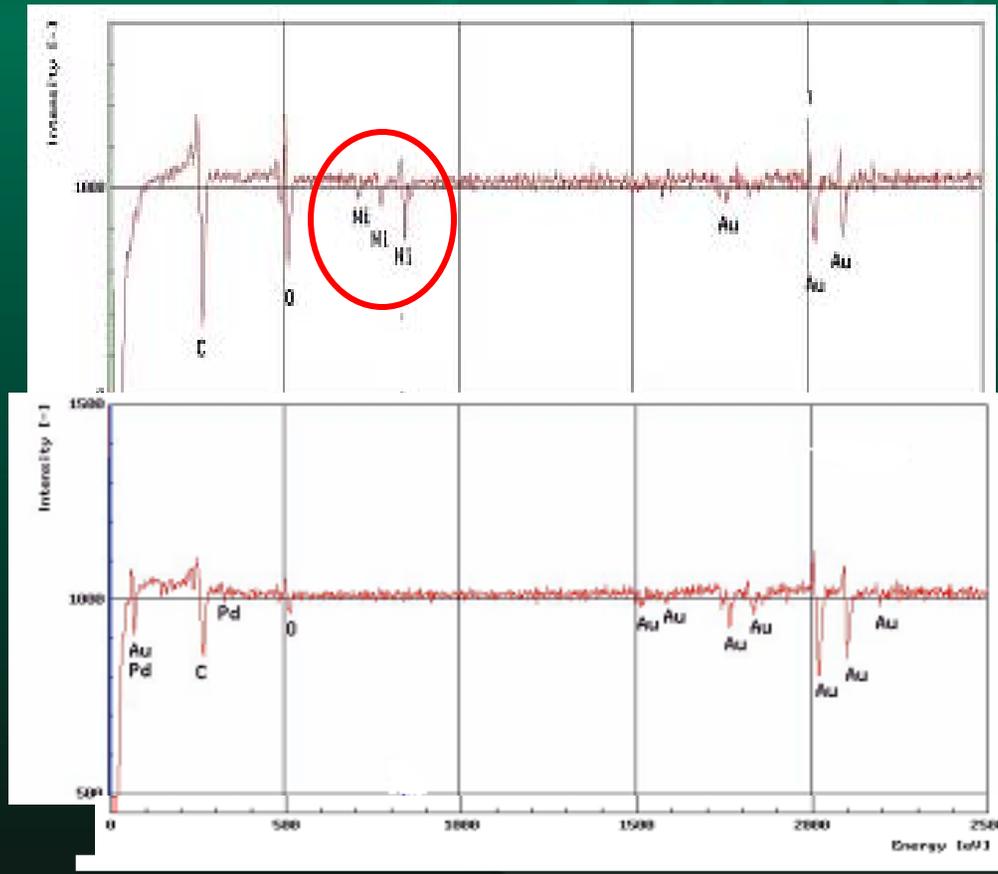


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# AES Analysis of ENAG and ENEPIG After Heat Treatment



ENAG

Ni = 5  $\mu\text{m}$   
Au = 0.2  $\mu\text{m}$

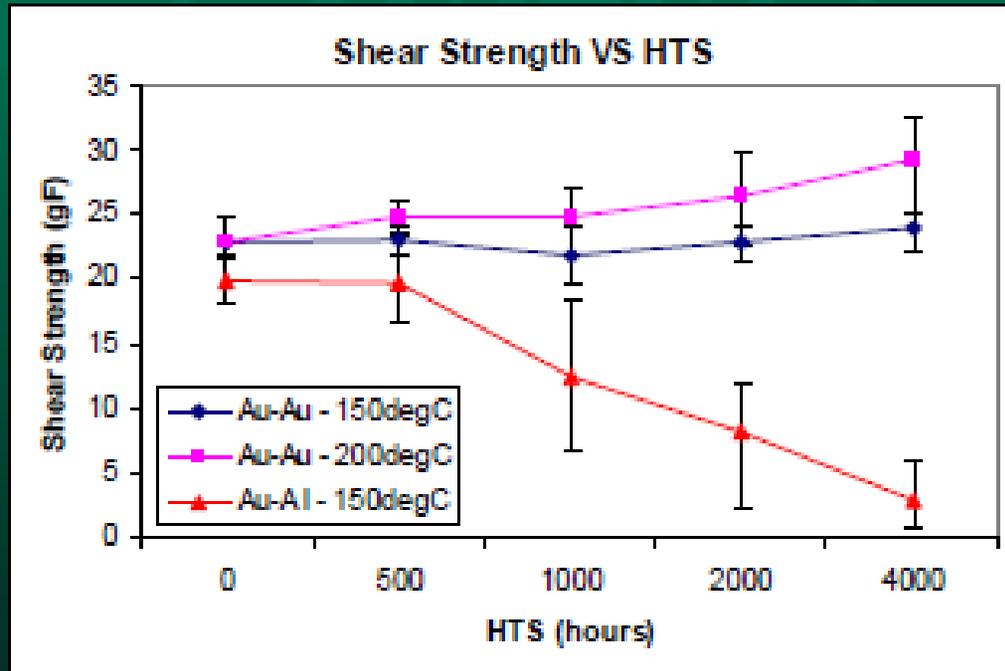
ENEPIG

Ni = 5  $\mu\text{m}$   
Pd = 0.06  $\mu\text{m}$   
Au = 0.05  $\mu\text{m}$

- Even with a thin layer of Pd the analysis shows that Ni does not diffuse to the wirebond surface when using ENIPIG



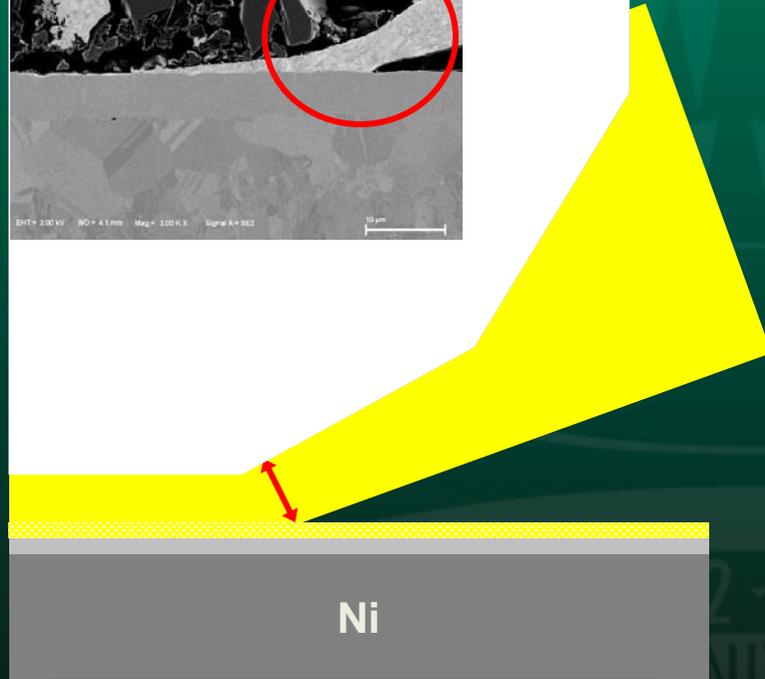
# Effects of HTS on Ball Shear Strength



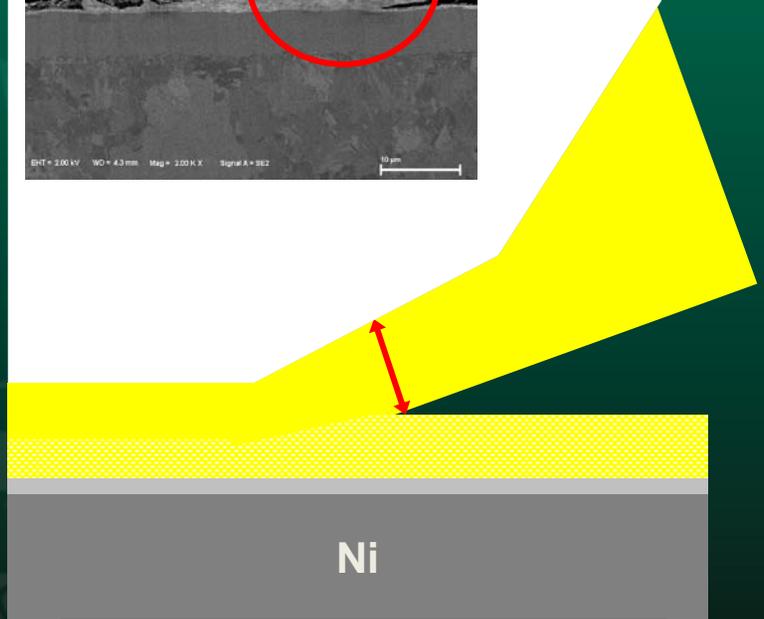
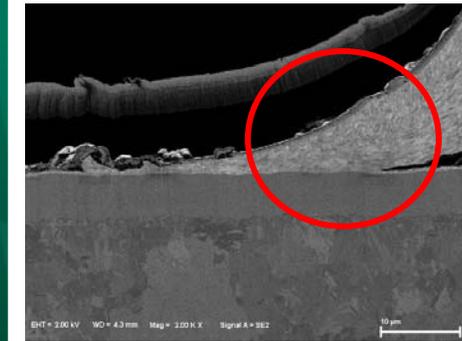
- Al-Au stable up to 500 hour then degradation begins
- Au-Au stable at all hours up to 4khrs
- Au-Au improves at higher temp likely due to solid state diffusion at the interface



## Illustration of Wire Neck Shape by Different Gold Thickness



Au 0.05um



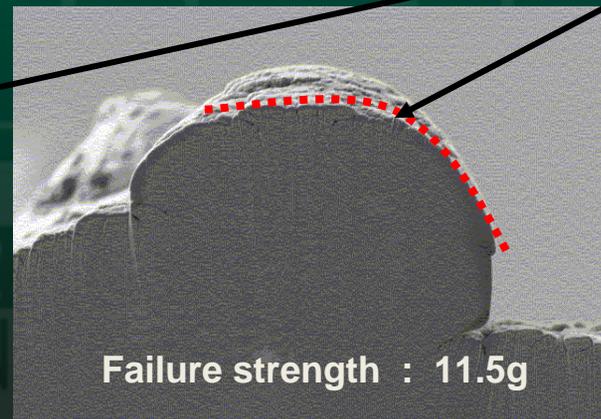
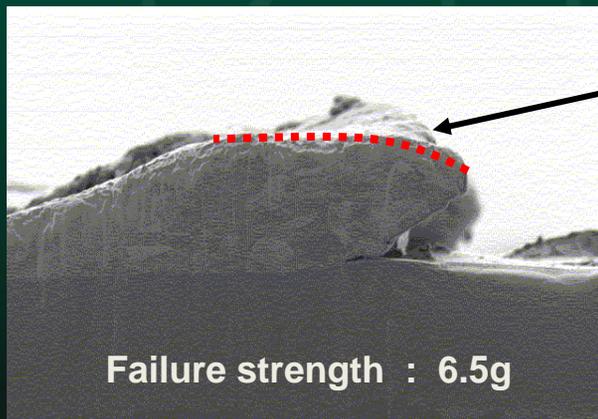
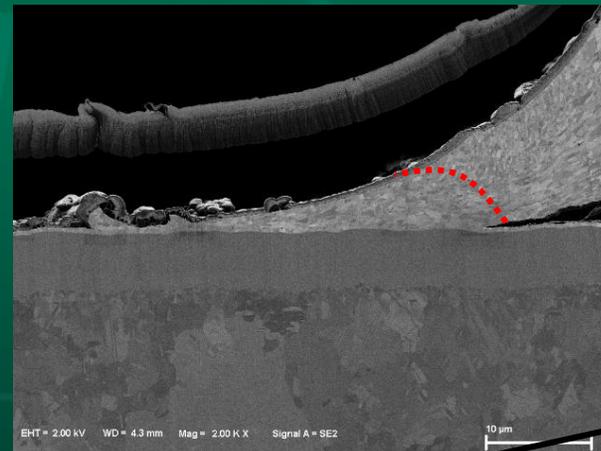
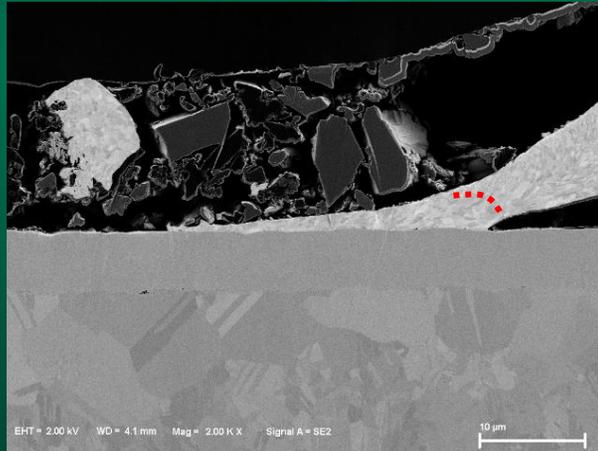
Au 0.4um

Au : 50-80Hv, Pd : 200-300Hv, Pd-P : 450-550Hv, Ni-P : 550-600Hv

- The thickness of wire neck are different according to the cushioning properties of gold.



# Failure Point at Different Strength After Wire Pull Test



Au 0.05um

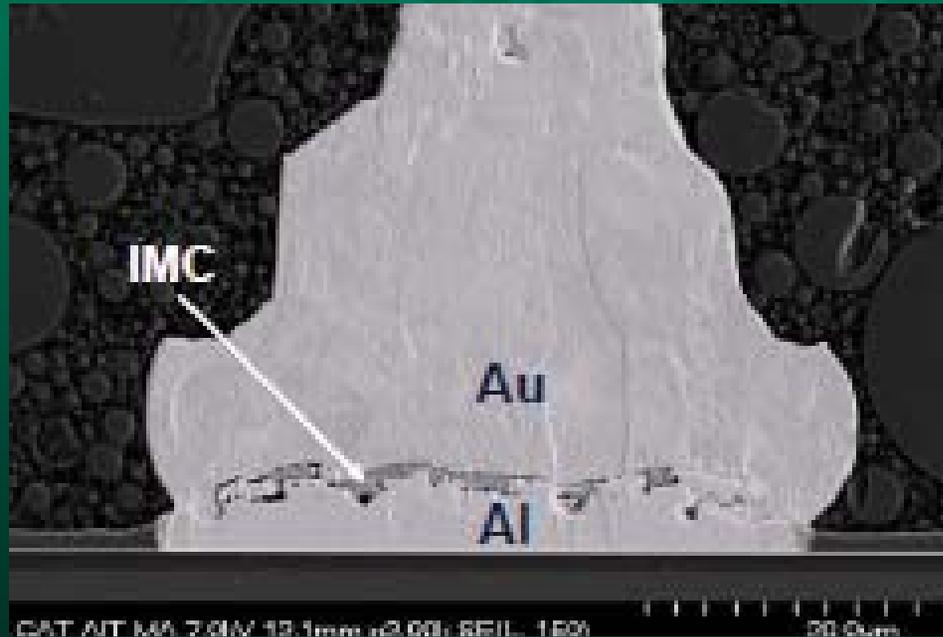
Au 0.4um

failure point

- The length of failure line are different compared with strong or weak strength point. The thickness of the wire just above the bonding area is markedly different.

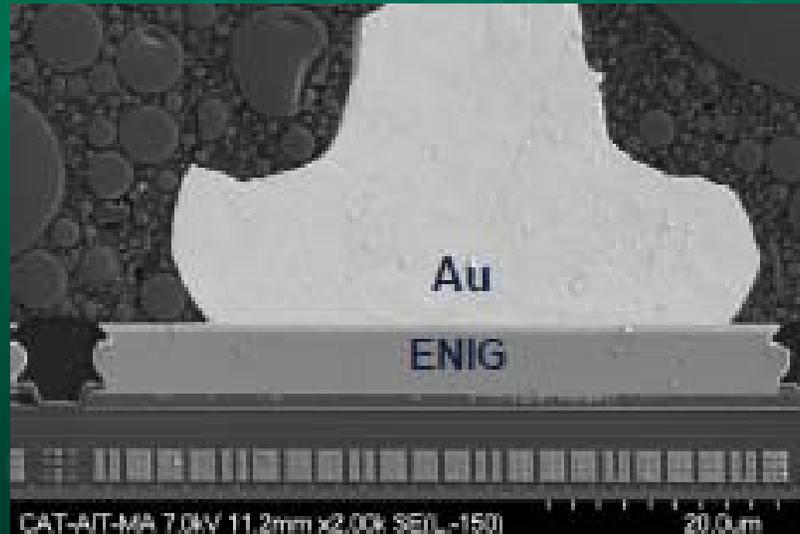


# Cross Section Au-Al at 500Hrs @150C



- No cleaning prior to wirebonding.
- Die were sawn in DI water with no chemistry
- Failures begin as early as 150 hours
- Failure at IMC

# Analysis of packaged units reliability



- No failures seen at 4khrs up to 200C
- No fracturing at interface.
- Reduced wirebond temp
- Less force on wire bond settings

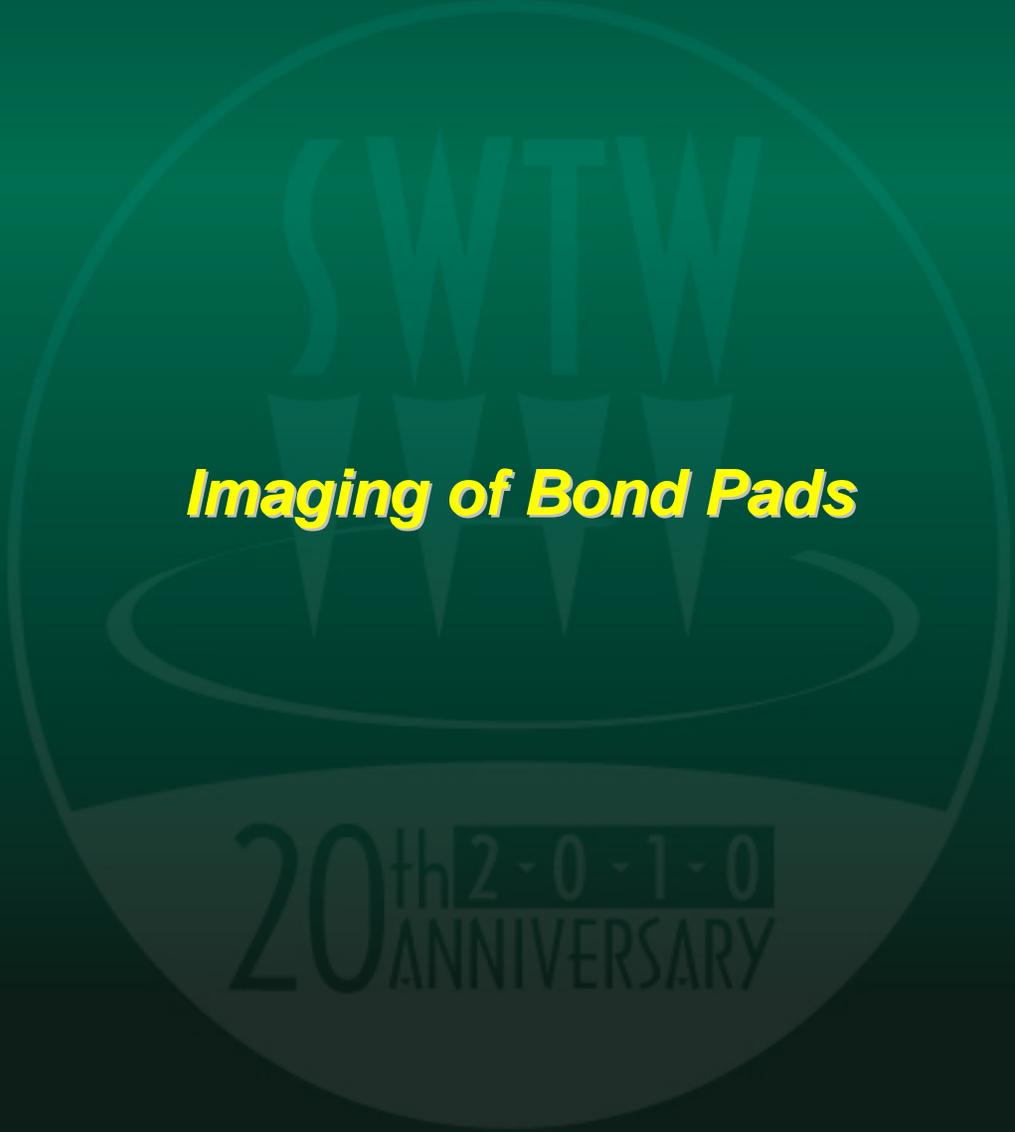


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Image courtesy IEEE 2006

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***Imaging of Bond Pads***

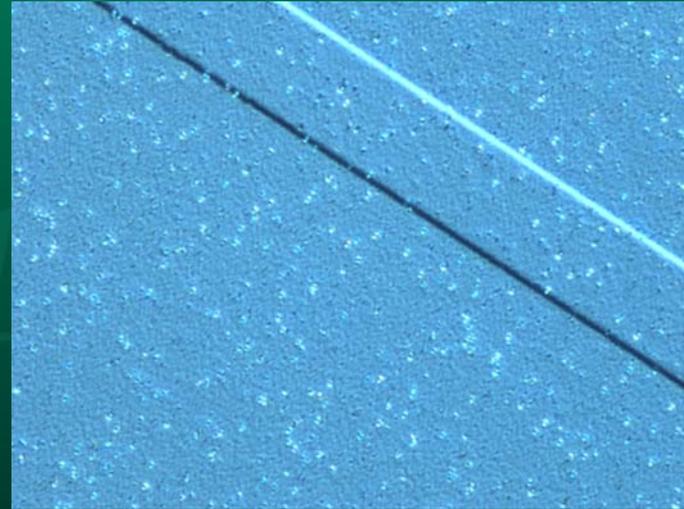


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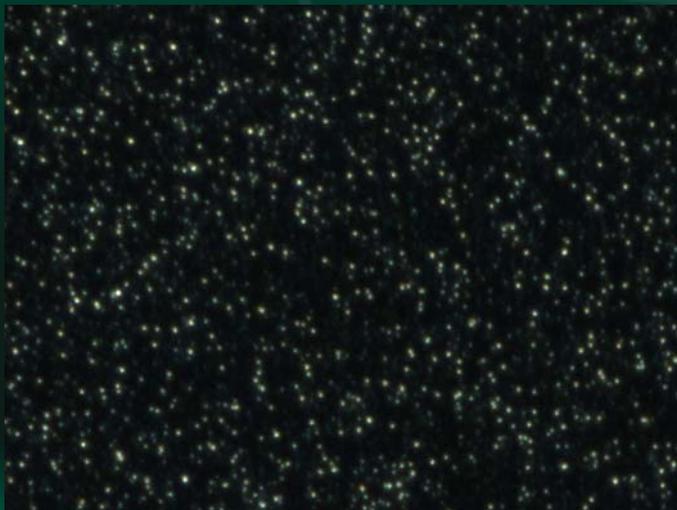
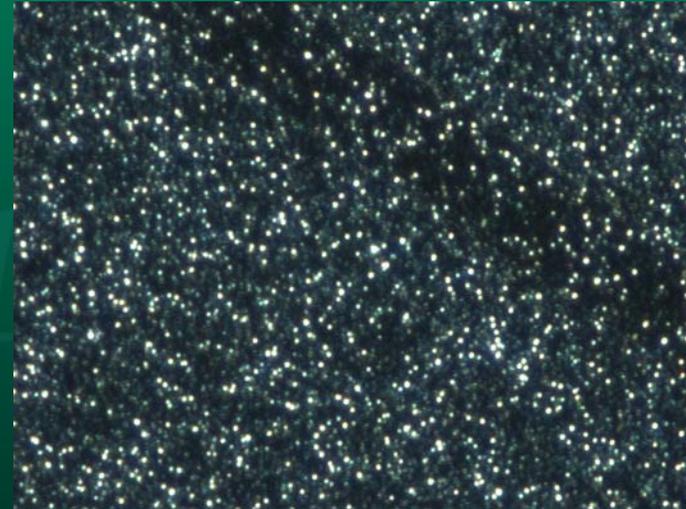
# Aluminum Oxide and OF



**Clockwise from upper left aluminum plus oxide, aluminum in air and aluminum after 2 min CF<sub>4</sub>+O<sub>2</sub> plasma. Same lighting conditions and magnification.**

**Note darkening of surface and oxide deltas between the surfaces.**

# Aluminum Oxide and OF -II



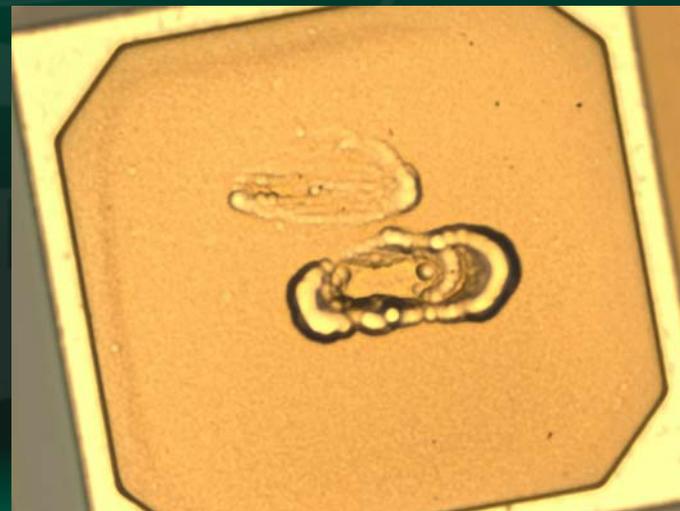
**Clockwise from upper left aluminum plus oxide, aluminum in air and aluminum after 2 min CF<sub>4</sub>+O<sub>2</sub> plasma. Same lighting conditions and magnification.**

**Note the refractive layer diminishes with processing and is replaced by the CRES layer.**



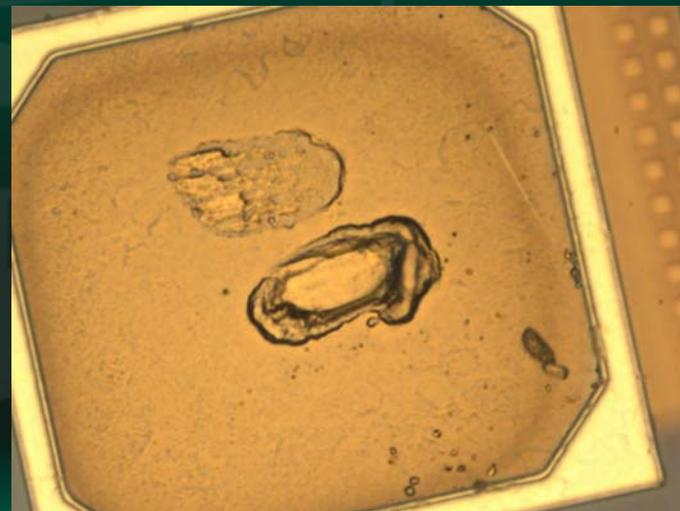
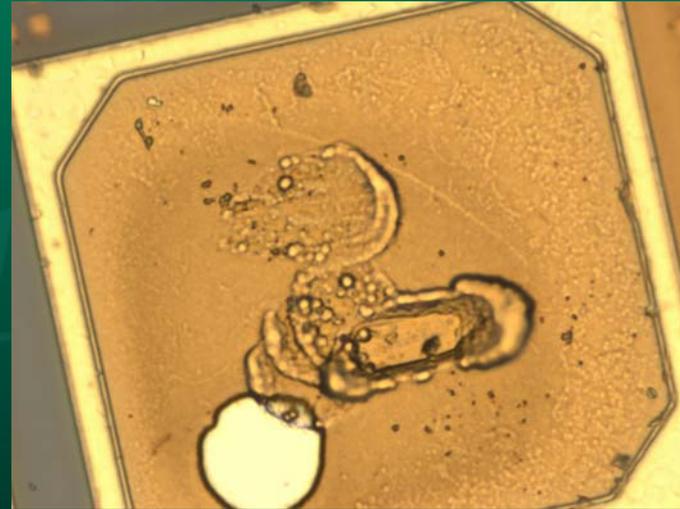
# Pad Conditions Pre and Post ENIPIG

- Top pad cleaned in BPS100 then allowed to sit in DI for 90 min
- Complete missing metal in probe mark
- Bottom pad has ENIPIG
- Probe mark is filled with new metal
- Smooth finish on plating



# Cleaning with w/ and w/o BPS100

- Pads on the top were not cleaned prior to ENIG process
- Incomplete coverage and rougher surface
- Bottom die has been cleaned with BPS100 prior to processing.
- Complete coverage



# Wirebondability

	Wire bondable t=0	Wire bondable t=24hrs	Wire bondable t=72
Bare aluminum	Marginal	No	No
Cleaned aluminum	Good	Marginal	No
Cleaned aluminum +DI water soak	No	No	No
ENIG	Yes	Slightly marginal	No
ENIPIG	Yes	Yes	yes
Ni/PdCo/Au	Yes	Yes	Yes

In many cases the NiPd and NiPdCo remains wirebondable without gold



## Summary

- Conditions at probe and wirebond show a similar root cause for poor process control
- Wire bonding on plated parts compared to bare aluminum shows marked improvement.
- Cleaning with BPS100 improves the ENIG process.
- **Wire bonding strength for ENEPIG is higher even with low Pd thickness range.**
- Nickel does not diffuse to the top surface with heat treatment even if Pd and Au are thin.
- **Increasing Au thickness shows improvement in wire bond strength while increased Pd thickness does not.**
- The thickness of wire neck are different according to cushioning properties of the gold deposit.



# Thank You!

Thank you for taking time to listening to this presentation.

Special thanks to:  
Uyemura International Corporation  
Don Gudeczauskas for assisting with  
ENIG/ENIPIG support.

Questions?

